## NSN 5961-00-731-6055

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View Online at https://aerobasegroup.com/nsn/5961-00-731-6055

Inclosure Material:
Metal
Overall Length:
Between 0.320 inches and 0.468 inches
Overall Diameter:
0.107 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Base
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
Between 0.424 inches and 0.437 inches
Thread Size:
0.190 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
80.0 collector to emitter voltage/static/base open and 100.0 collector to emitter reverse voltage, with base short-circuited to emitter and 6.0
emitter to base voltage, static, collector open
Current Rating Per Characteristic:
5.00 amperes source cutoff current
Power Rating Per Characteristic:
45.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Test Data Document:
03640-6096365 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Thread Series Designator:
Unf
Terminal Type And Quantity:
3 tab, solder lug
Shelf Life:
N/a

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**Unit Of Measure:** 

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Demilitarization:

No

Fiig:

A110a0